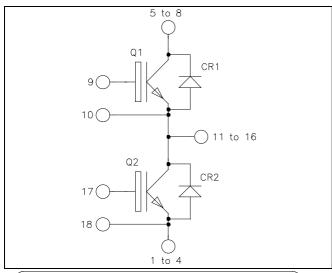
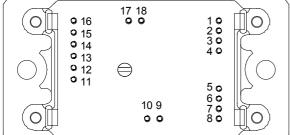


Phase leg Fast Trench + Field Stop IGBT3 Power Module







Pins 1/2/3/4 ; 5/6/7/8 ; 11/12/13/14/15/16 must be shorted together

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Fast Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- RoHS Compliant

All ratings @ $T_j = 25$ °C unless otherwise specified

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V
I_{C}	Continuous Collector Current	$T_C = 25$ °C	220	
	Continuous Conector Current	$T_C = 80$ °C	150	A
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	350	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25$ °C	690	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	300A @ 1150V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				50	μΑ
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		1.7	2.1	V
		$I_{\rm C} = 150 A$	$T_j = 125$ °C		2.0		
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 3 \text{ mA}$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$			10.7		nF
C_{oes}	Output Capacitance				0.56		
C_{res}	Reverse Transfer Capacitance	f = 1MHz			0.48		
Q_{G}	Gate charge	V_{GE} =±15V, I_{C} =150A V_{CE} =600V			1.4		μС
$T_{d(on)}$	Turn-on Delay Time	4	Inductive Switching (25°C)		280		
T_{r}	Rise Time	$V_{GE} = \pm 15V$			40		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 150A$	$V_{Bus} = 600V$		420		ns
T_{f}	Fall Time	$R_G = 2.2\Omega$			75		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_C = 150A$			290		ns
T_{r}	Rise Time				45		
$T_{d(off)}$	Turn-off Delay Time				520		
T_{f}	Fall Time	$R_G = 2.2\Omega$	-		90		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C		14		mJ
E_{off}	Turn-off Switching Energy	$I_C = 150A$ $R_G = 2.2\Omega$	$T_j = 125$ °C		16		1113
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; $V_{Bus} = 900V$ $t_p \le 10 \mu s$; $T_i = 125 ^{\circ}C$			600		A
R_{thJC}	Junction to Case Thermal Resistance					0.18	°C/W

Reverse diode ratings and characteristics

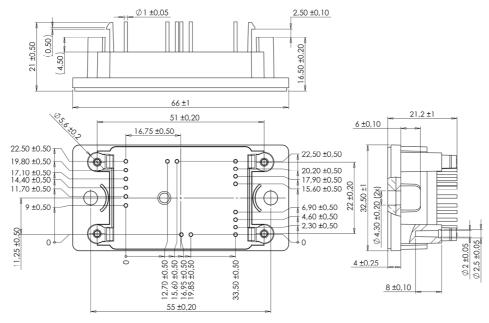
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I_{RM}	Maximum Reverse Leakage Current	V _R =1200V				50	μΑ
I_F	DC Forward Current		Tc = 80°C		150		A
V_{F}	Diode Forward Voltage	$I_F = 150A$	$T_j = 25$ °C		1.6	2.1	V
* F			$T_{i} = 125^{\circ}C$		1.6		,
t _{rr}	Reverse Recovery Time	$I_F = 150 A$ $V_R = 600 V$ $di/dt = 3000 A/\mu s$	$T_j = 25$ °C		170		ns
·II			$T_j = 125$ °C		280		
0	Reverse Recovery Charge		$T_j = 25$ °C		15		μC
Q_{rr}			$T_{j} = 125^{\circ}C$		29		μC
E _r	Reverse Recovery Energy		$T_i = 25^{\circ}C$		7		ma I
			$T_{j} = 125^{\circ}C$		12		mJ
R_{thJC}	Junction to Case Thermal Resistance		•			0.34	°C/W



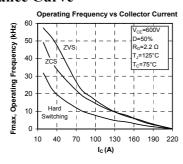
Thermal and package characteristics

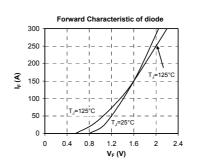
Symbol	Characteristic		Min	Тур	Max	Unit	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range		-40		150		
T_{STG}	Storage Temperature Range			-40		125	°C
T_{C}	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					75	g

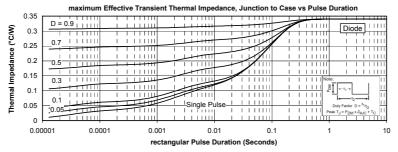
SP2 Package outline (dimensions in mm)



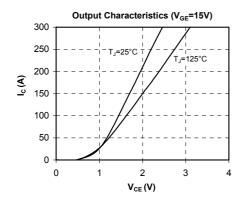
Typical Performance Curve

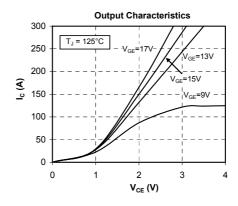


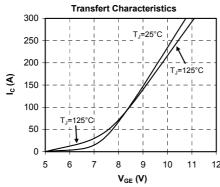


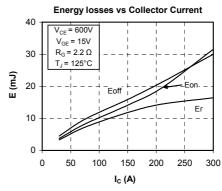


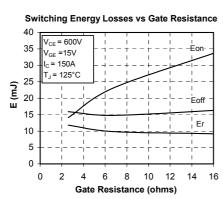


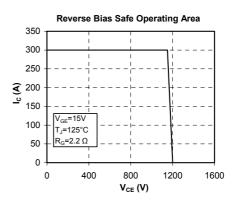


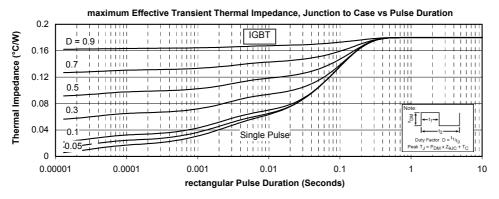














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